

L Number	Hits	Search Text	DB	Time stamp
64	27448	((light-emitting) (light near emitting)) and (recess trench gap cavity opening groove) and sensor	USPAT; US-PPGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/10/17 15:38
65	1714296	optical lens	USPAT; US-PPGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/10/17 15:40
66	19649	((((light-emitting) (light near emitting)) and (recess trench gap cavity opening groove) and sensor ) and (optical lens))	USPAT; US-PPGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/10/17 15:40
67	4736655	substrate wafer base (auxiliary near carrier)	USPAT; US-PPGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/10/17 15:43
68	14795	((((light-emitting) (light near emitting)) and (recess trench gap cavity opening groove) and sensor ) and (optical lens)) and (substrate wafer base (auxiliary near carrier))	USPAT; US-PPGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/10/17 16:34
72	22621	optoelectronic	USPAT; US-PPGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/10/17 16:34
73	647	((((((light-emitting) (light near emitting)) and (recess trench gap cavity opening groove) and sensor ) and (optical lens)) and (substrate wafer base (auxiliary near carrier))) and optoelectronic	USPAT; US-PPGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/10/17 16:34